

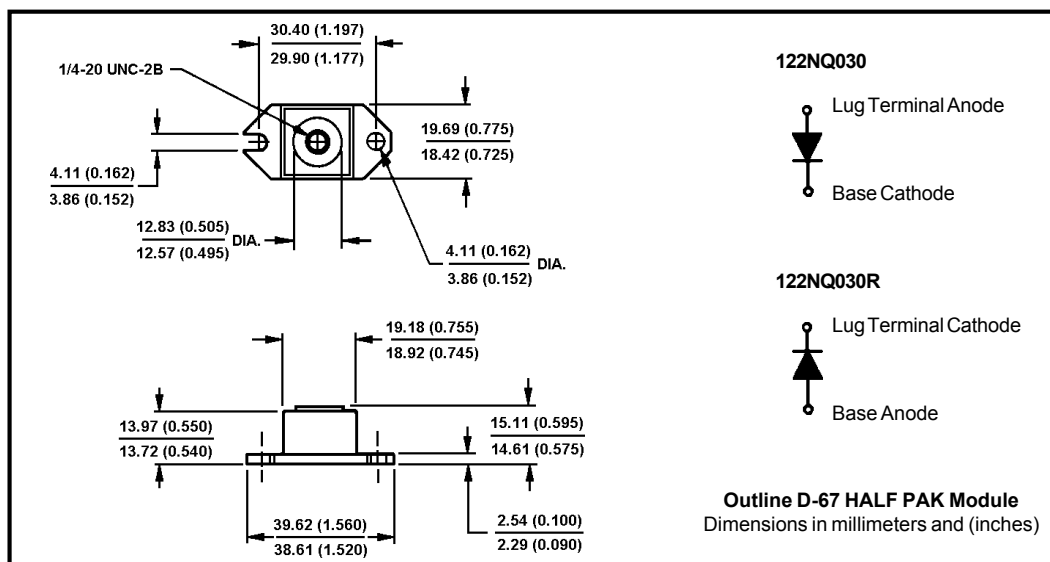
Major Ratings and Characteristics

Characteristics	122NQ030(R)	Units
$I_{F(AV)}$ Rectangular waveform	120	A
V_{RRM}	30	V
I_{FSM} @ $t_p = 5 \mu s$ sine	22,500	A
V_F @120Apk, $T_J = 125^\circ C$	0.41	V
T_J range	-55 to 150	$^\circ C$

Description/Features

The 122NQ030 (R) high current Schottky rectifier module has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to $150^\circ C$ junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- $150^\circ C$ T_J operation
- Unique high power, Half-Pak module
- Replaces two parallel DO-5's
- Easier to mount and lower profile than DO-5's
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



122NQ030

Bulletin PD-2.274 rev. B 03/01

International
IR Rectifier

Voltage Ratings

Part number	122NQ030
V_R Max. DC Reverse Voltage (V)	30
V_{RWM} Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters	122NQ	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current * See Fig. 5	120	A	50% duty cycle @ $T_C = 110^\circ\text{C}$, rectangular wave form
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 7	22,500	A	5 μs Sine or 3 μs Rect. pulse
	2400		10ms Sine or 6ms Rect. pulse
E_{AS} Non-Repetitive Avalanche Energy	54	mJ	$T_J = 25^\circ\text{C}$, $I_{AS} = 12\text{ Amps}$, $L = 0.75\text{ mH}$
I_{AR} Repetitive Avalanche Current	12	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical

Electrical Specifications

Parameters	122NQ	Units	Conditions
V_{FM} Max. Forward Voltage Drop (1) * See Fig. 1	0.49	V	@ 120A
	0.59	V	@ 240A
	0.41	V	@ 120A
	0.54	V	@ 240A
I_{RM} Max. Reverse Leakage Current (1) * See Fig. 2	10	mA	$T_J = 25^\circ\text{C}$
	560	mA	$T_J = 125^\circ\text{C}$
C_T Max. Junction Capacitance	7400	pF	$V_R = 5V_{DC}$, (test signal range 100Khz to 1Mhz) 25°C
L_S Typical Series Inductance	7.0	nH	From top of terminal hole to mounting plane
dv/dt Max. Voltage Rate of Change (Rated V_R)	10,000	V/ μs	

(1) Pulse Width < 300 μs , Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters			122NQ	Units	Conditions
T _J	Max. Junction Temperature Range		-55 to 150	°C	
T _{stg}	Max. Storage Temperature Range		-55 to 150	°C	
R _{thJC}	Max. Thermal Resistance Junction to Case		0.40	°C/W	DC operation * See Fig. 4
R _{thCS}	Typical Thermal Resistance, Case to Heatsink		0.15	°C/W	Mounting surface, smooth and greased
wt	Approximate Weight		25.6(0.9)	g(oz.)	
T	Mounting Torque	Min.	40(35)	Kg-cm (lbf-in)	Non-lubricated threads
		Max.	58(50)		
	Terminal Torque	Min.	58(50)		
		Max.	86(75)		
Case Style			HALF PAK Module		

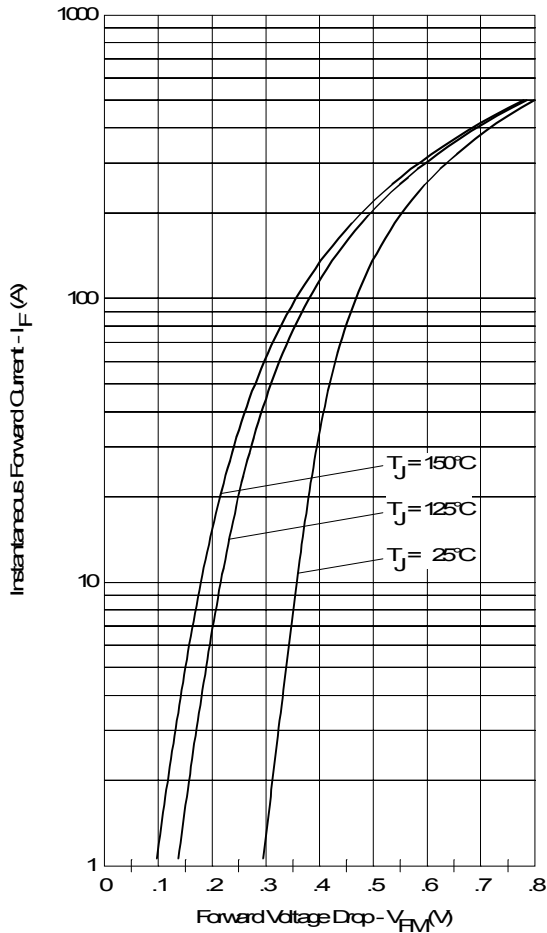


Fig. 1 - Maximum Forward Voltage Drop Characteristics

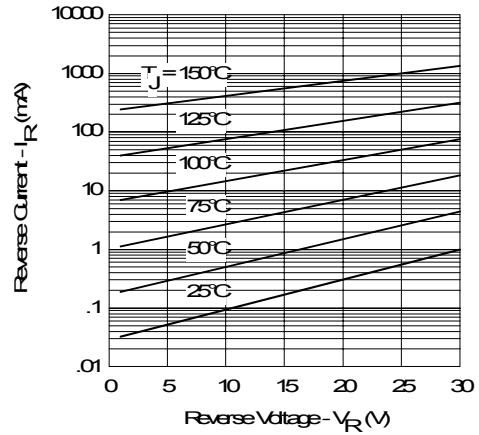


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

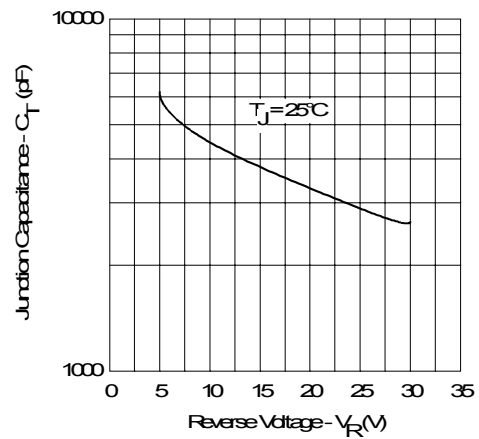


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

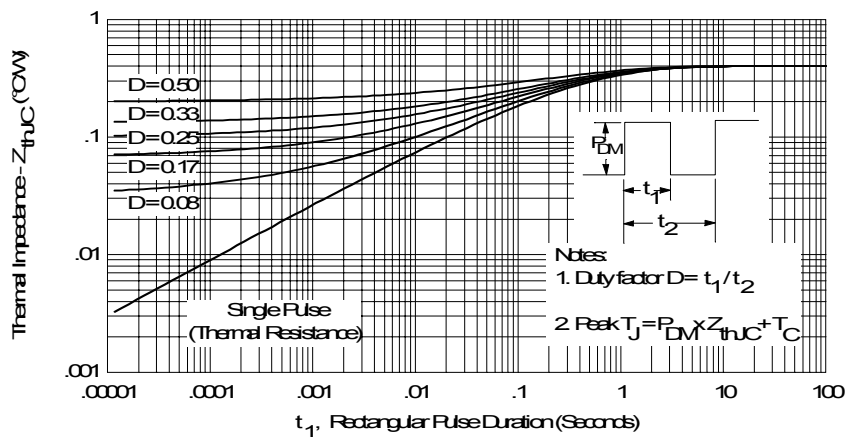


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

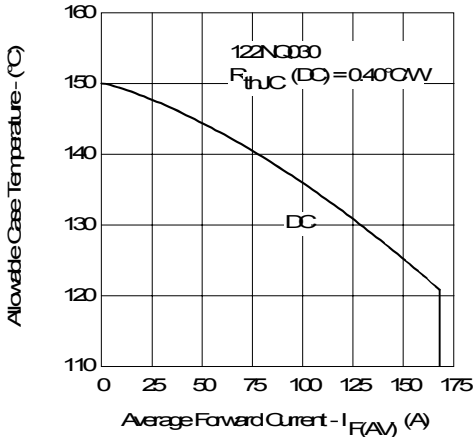


Fig. 5-Maximum Allowable Case Temperature Vs. Average Forward Current

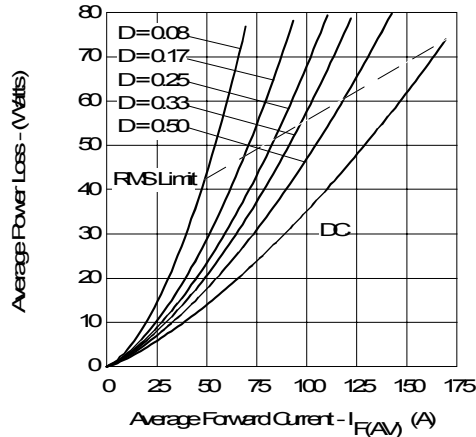


Fig. 6-Forward Power Loss Characteristics

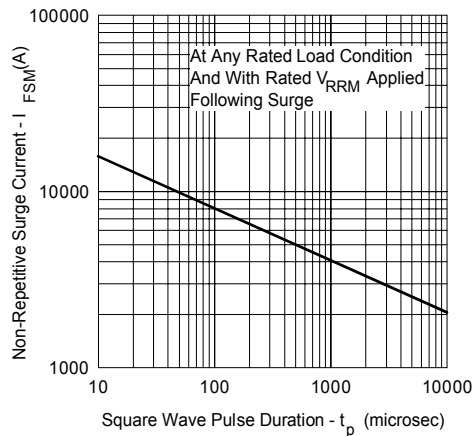


Fig. 7-Maximum Non-Repetitive Surge Current

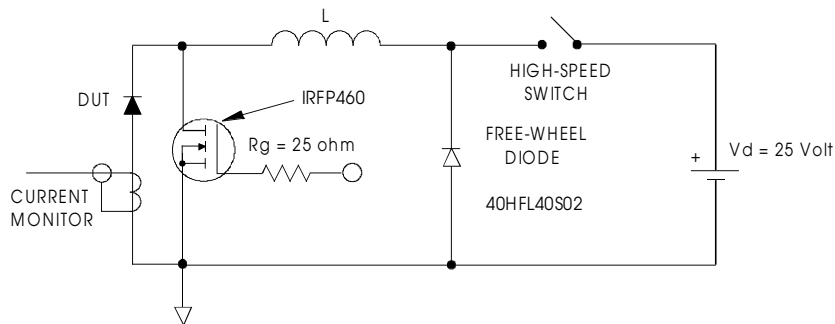


Fig. 8-Unclamped Inductive Test Circuit